



A Product Line of Diodes Incorporated

ZX5T1951G

60V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

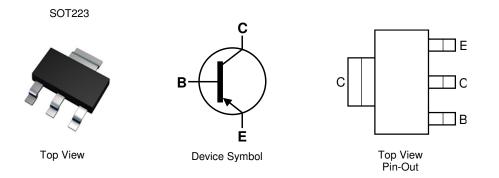
- BV_{CEO} > -60V
- I_C = -6A Continuous Collector Current
- Low Saturation Voltage V_{CE(sat)} < -95mV max @ -1A
- R_{CE(sat)} = 40mΩ for a low Equivalent On-Resistance
- h_{FE} Specified up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)

Applications

- Motor Driving
- DC-DC Modules
- Backlight Inverters
- Actuator, Relay, and Solenoid Drivers



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T1951GTA	ZX5T1951	7	12	1,000

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

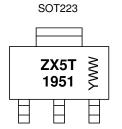
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-Free, "Green" and Lead-Free.

3. Halogen- and Antimony-Free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



 $\begin{array}{l} ZX5T1951 = \mbox{Product Type Marking Code} \\ YWW = \mbox{Date Code Marking} \\ Y \mbox{ or } \overline{Y} = \mbox{Last Digit of Year (ex: 5= 2015)} \\ WW \mbox{ or } \overline{W}W = \mbox{Week Code (01~53)} \end{array}$



Absolute Maximum Ratings (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-90	V
Collector-Emitter Voltage	V _{CES}	-90	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current (Note 5)	Ic	-6	A
Peak Pulse Current	ICM	-15	A
Base Current	IB	-1	A

Thermal Characteristics (@TA = +25 °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	5	3.0 24	W	
Linear Derating Factor	(Note 6)	P _D	1.6 12.8	mW /℃	
Thermal Resistance. Junction to Ambient	(Note 5)	R _{eJA}	42		
mermai Resistance, Junction to Ambient	(Note 6)	R _{0JA}	78	°C/W	
Thermal Resistance Junction to Lead	(Note 7)	R _{θJL}	12.3		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

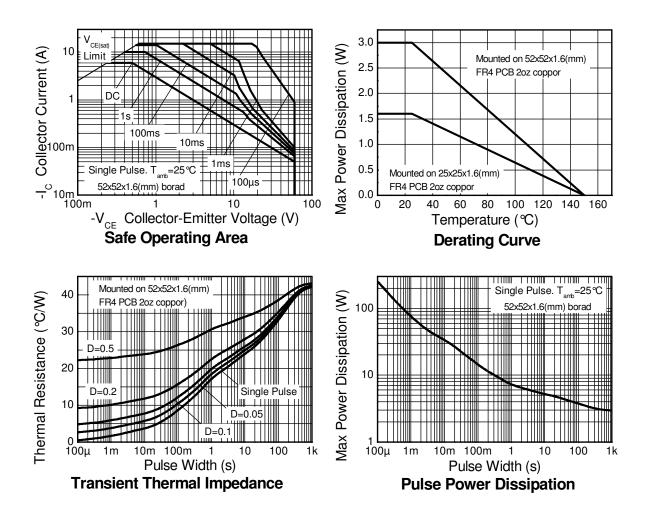
7. Thermal resistance from junction to solder-point (at the end of the collector lead).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics





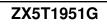


Electrical Characteristics	$(@T_A = +25 \degree C, unless otherwise specified.)$
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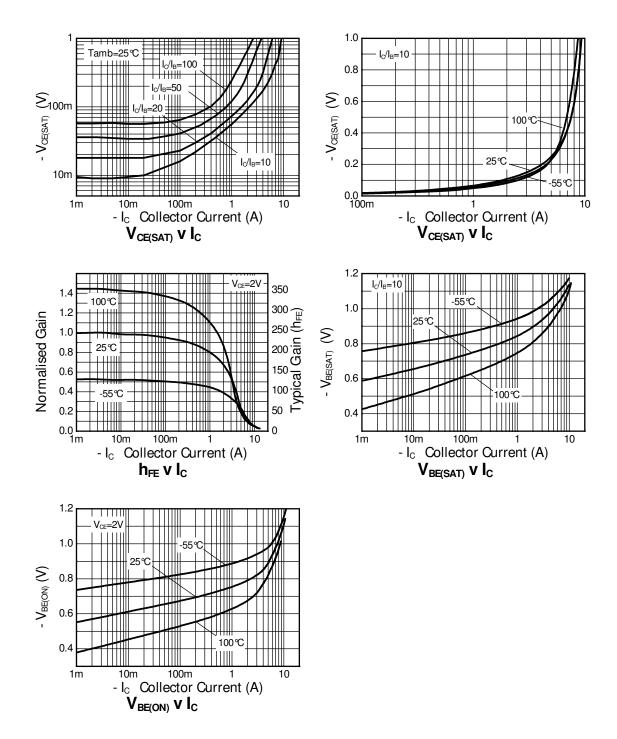
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-90	-120	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CES}	-90	-120	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	-80	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	-	V	I _E = -100μA
Collector-Base Cut-Off Current	I _{CBO}	-	<1	-50	nA	$V_{CB} = -72V$
Collector-Emitter Cut-Off Current	I _{CES}	-	<1	-50	nA	$V_{CB} = -72V$
Emitter Cutoff Current	I _{EBO}	-	<1	-10	nA	$V_{EB} = -6V$
		100	240	-		$I_{C} = -10mA, V_{CE} = -2V$
Statia Forward Current Transfer Datia (Nata 0)	h _{FE}	100	180	300	-	$I_{C} = -2A, V_{CE} = -2V$
Static Forward Current Transfer Ratio (Note 9)		40	70	-		$I_{C} = -5A, V_{CE} = -2V$
		5	14	-		$I_{C} = -10A, V_{CE} = -2V$
	V _{CE(sat)}	-	-16	-30	mV	$I_{C} = -100 \text{mA}, I_{B} = -10 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)		-	-55	-95		$I_{C} = -1A, I_{B} = -100mA$
		-	-85	-130	111 V	$I_{C} = -2A, I_{B} = -200mA$
		-	-200	-260		$I_{C} = -5A, I_{B} = -500mA$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	-1	-1.15	V	$I_{\rm C} = -5A, I_{\rm B} = -500 {\rm mV}$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	-	-0.89	-1.0	V	$I_{C} = -5A, V_{CE} = -2V$
Output Capacitance (Note 9)	Cobo	-	33	70	pF	V _{CB} = -10V. f = 1MHz
Transition Frequency	f _T	-	120	-	MHz	V _{CE} = -10V, I _C = -100mA f = 50MHz
	t _{on}	-	33	80		$V_{CC} = -10V, I_{C} = -2A$
Switching Time	t _{off}	-	215	300	ns	$I_{B1} = -I_{B2} = -200 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.





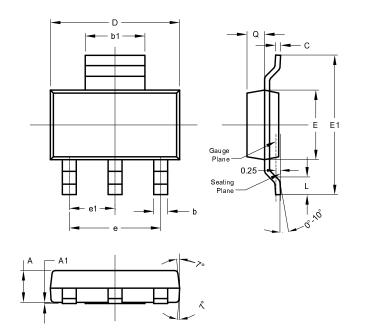
Typical Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)





Package Outline Dimensions

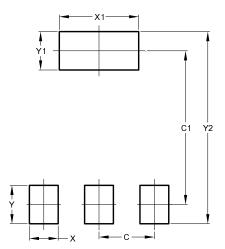
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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